# **Technical Data Sheet**



DPDT Ramses N 3GHz Failsafe Indicators 12Vdc TTL Diodes D-sub connector with bracket

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# RF CHARACTERISTICS

Frequency range : 0 - 3 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 1	1 - 2	2 - 3
VSWR max	1.15	1.20	1.25
Insertion loss max	0.15 dB	0.20 dB	0.25 dB
Isolation min	85 dB	80 dB	75 dB
Average power (*)	700 W	500 W	400 W

# **ELECTRICAL CHARACTERISTICS**

Actuator : FAILSAFE
Nominal current \*\* : 340 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V)

Terminals : 9 pins D-SUB male connector

Indicator rating : 1 W / 30 V / 100 mA

TTL inputs (E) - High level :  $2.2 \text{ to } 5.5 \text{ V} \text{ / } 800 \mu\text{A} \text{ at } 5.5 \text{ V}$ 

- Low level : 0 to 0.8 V / 20 $\mu$ A at 0.8 V

### MECHANICAL CHARACTERISTICS

Connectors : N female per MIL-C 39012

Life : 2.5 million cycles

#### **ENVIRONMENTAL CHARACTERISTICS**

Operating temperature range : -40°C to +85°C Storage temperature range : -55°C to +85°C

(\* Average power at 25°C per RF Path)

(\*\* At 25° C ±10%)

(\*\*\* Nominal voltage; 25° C)



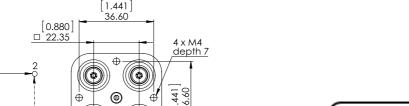




DPDT Ramses N 3GHz Failsafe Indicators 12Vdc TTL Diodes D-sub connector with bracket

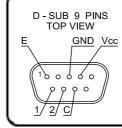
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# **DRAWING** [1.441] 36.60 [0.880] □ 22.35 4 x M4 depth 7 Ф **6**

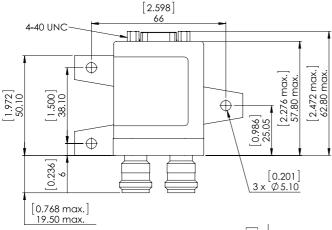


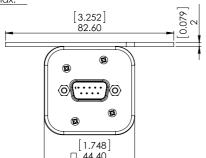


# LABEL



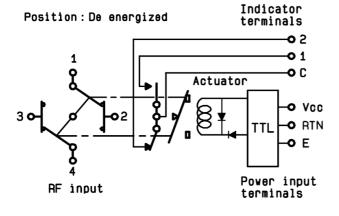
**RADIALL®** R577022105 0 - 3 GHz Un: 12V Lot : \_ \_ \_ \_





General tolerances: ±0,5 mm [0,02 in]

# SCHEMATIC DIAGRAM



TTL input	RF Continuity	Ind.
E = 1	$1 \leftrightarrow 3 / 2 \leftrightarrow 4$	C.1
E = 0	$1 \leftrightarrow 2 \ / \ 3 \leftrightarrow 4$	C.2